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ON Semiconductor®

FDD9411L-F085

N-Channel Logic Level PowerTrench[®] MOSFET

40 V, 25 A, 7.0 m Ω

Features

- Typical $R_{DS(on)}$ = 5.6 mΩ at V_{GS} = 10V, I_D = 20 A
- Typical Q_{g(tot)} = 18 nC at V_{GS} = 10V, I_D = 20 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter/Alternator
- Distributed Power Architectures and VRM
- Primary Switch for 12V Systems

MOSFET Maximum Ratings T_J = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-to-Source Voltage		40	V
V _{GS}	Gate-to-Source Voltage		±20	V
1	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	25	^
D	Pulsed Drain Current	T _C = 25°C	See Figure 4	A
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	22	mJ
P _D	Power Dissipation		48.4	W
	Derate Above 25°C		0.32	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case		3.1	°C/W
R _{0JA}	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	52	°C/W

Notes:

- 1: Current is limited by bondwire configuration.
- 2: Starting $T_J = 25^{\circ}$ C, L = 0.1mH, $I_{AS} = 21A$, $V_{DD} = 40V$ during inductor charging and $V_{DD} = 0V$ during time in avalanche.
- 3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD9411L	FDD9411L-F085	D-PAK(TO-252)	13"	16mm	2500units

D

D

D-PAK

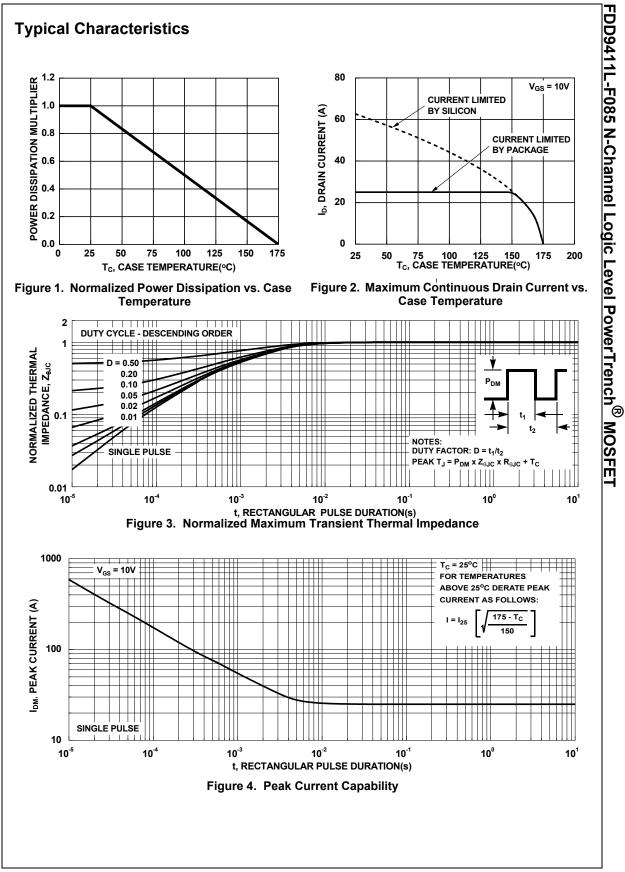
(TO-252)



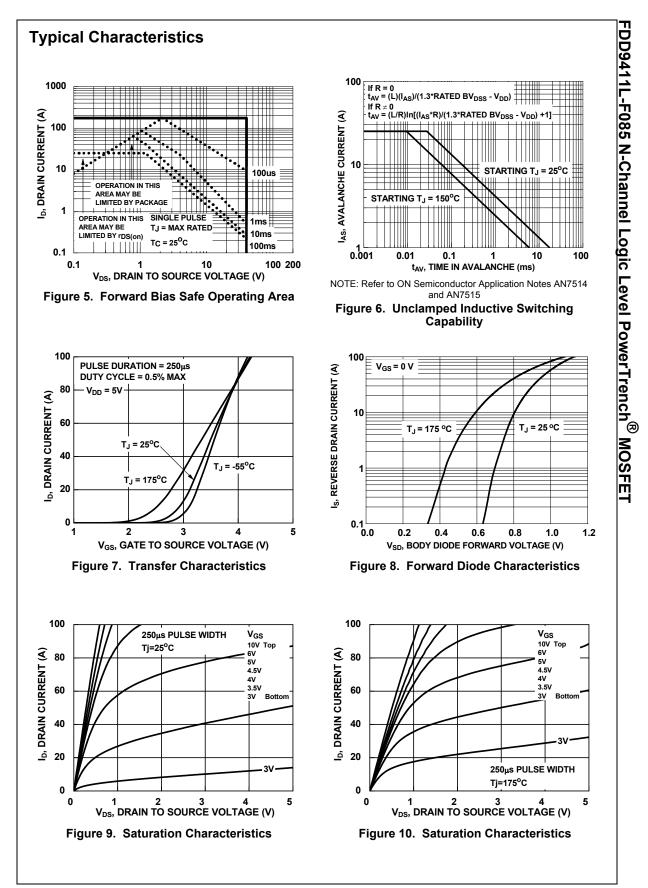
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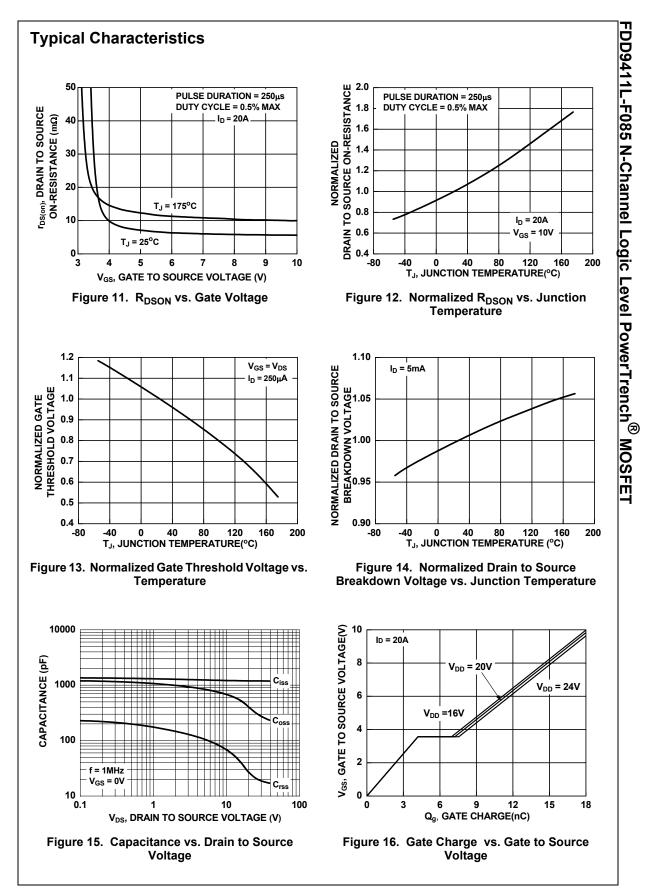
S

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	racteristics						
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		40	-	-	V
I _{DSS}	Drain-to-Source Leakage Current	V _{DS} =40V,		-	-	1	μA mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$ 1j = 173 C (Note 4)		-	-	±100	nA
On Cha	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA I _D = 20A, V _{GS} = 4.5V		1.0	1.8	3.0	V
				-	7.9	11.5	mΩ
R _{DS(on)}	Drain to Source On Resistance	I _D = 20A,	T _J = 25 ^o C	-	5.6	7.0	mΩ
- (-)		V _{GS} = 10V		-	9.8	12.4	mΩ
Dynami	c Characteristics						
C _{iss}	Input Capacitance	V _{DS} = 20V, V _{GS} = 0V, f = 1MHz		-	1210	-	pF
C _{oss}	Output Capacitance			-	413	-	pF
C _{rss}	Reverse Transfer Capacitance			-	28	-	pF
R _g	Gate Resistance	f = 1MHz		-	2.6	-	Ω
Q _{g(ToT)}	Total Gate Charge	V _{GS} = 0 to 1	0V V _{DD} = 32V	-	18	27	nC
Q _{g(th)}	Threshold Gate Charge	V _{GS} = 0 to 2		-	2	-	nC
Q _{gs}	Gate-to-Source Gate Charge			-	4	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge			-	3	-	nC
Switchi	ng Characteristics						
t _{on}	Turn-On Time			-	-	17	ns
t _{d(on)}	Turn-On Delay				7	-	ns
t _r	Rise Time	V_{DD} = 20V, I_D = 20A, V_{GS} = 10V, R_{GEN} = 6 Ω		-	4	-	ns
t _{d(off)}	Turn-Off Delay			-	20	-	ns
t _f	Fall Time				4	-	ns
t _{off}	Turn-Off Time			-	-	36	ns
t _{off} Drain-S	Turn-Off Time ource Diode Characteristics			-	-	36	ns
V _{SD}	Source-to-Drain Diode Voltage	I _{SD} =20A, V		-	-	1.25	V
• 50		I _{SD} = 10A, V	/ _{GS} = 0V	-	-	1.2	V
t _{rr}	Reverse-Recovery Time	I _F = 20A, dI _{SD} /dt = 100A/μs V _{DD} = 32V		-	36	54	ns
Q _{rr}	Reverse-Recovery Charge			-	23	34	nC



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